TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

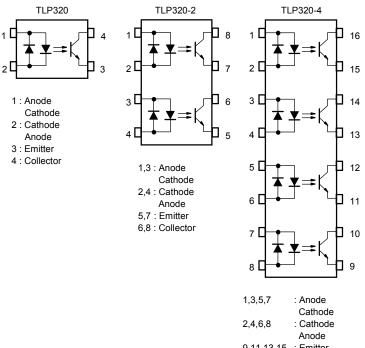
TLP320, TLP320-2, TLP320-4

Telecommunication Office Machine Telephone Use Equipment

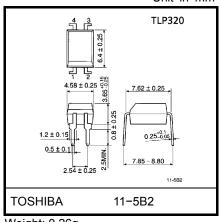
The TOSHIBA TLP320, -2 and -4 consists of a photo-transistor optically coupled to a gallium arsenide infrared emitting diode. The TLP320-2 offers two isolated channels in an eight lead plastic DIP package, while the TLP320-4 provides four isolated channels in a sixteen plastic DIP package. This is suitable for application of AC input current up to 150mA.

- IF maximum rating: ±150mA
- Collector-emitter voltage: 55V (min.)
- Current transfer ratio: 25% (min.) (IF = 20mA)
- Isolation voltage: 5000V_{rms} (min.)
- UL recognized: file No. E67349
- BSI approved: BS EN60065:2002, certificate no.7426 BS EN60950-1:2002, certificate no.7427

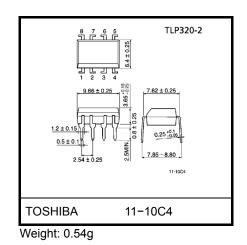
Pin Configurations (top view)

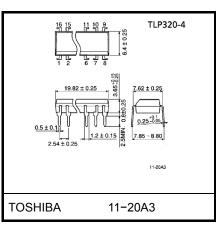


9,11,13,15 : Emitter 10,12,14,16 : Collector











Unit in mm

Absolute Maximum Ratings (Ta = 25°C)

			Rat			
Characteristic		Symbol	TLP320	TLP320–2 TLP320–4	Unit	
	Forward current	١ _F	±1	50	mA	
Ω	Forward current derating	ΔI _F /°C	–1.5 (Ta ≥ 25°C)		mA / °C	
LED	Pulse forward current	I _{FP}	±1 (100µs pulse, 100pps)		А	
	Junction temperature	Tj	12	125		
	Collector-emitter voltage	V _{CEO}	5	5	V	
	Emitter-collector voltage	V _{ECO}	7	7	V	
۲	Collector current	Ι _C	8	0	mA	
Detector	Collector power dissipation (1 circuit)	P _C	150	100	mW	
	Collector power dissipation derating (1 circuit, Ta ≥ 25°C)	ΔP _C / °C	-1.5	-1.0	mW / °C	
	Junction temperature	Tj	12	25	°C	
Stor	rage temperature range	T _{stg}	-55~	-55~125		
Operating temperature range		T _{opr}	-55~100		°C	
Lead soldering temperature		T _{sol}	260 (260 (10s)		
Total package power dissipation		PT	250	200	mW	
	al package power dissipation ating (Ta≥25°C)	ΔP _T / °C	-2.5	2.0	mW / °C	
Isol	ation voltage (Note 1)	BVS	5000 (AC, 1min., R.H. ≤ 60%)		V _{rms}	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Recommended Operating Conditions

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	V _{CC}	_	5	24	V
Forward current	١ _F	_	20	120	mA
Collector current	Ι _C	_	1	10	mA
Operating temperature	T _{opr}	-25	_	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

⁽Note 1) Device consider a two terminal: LED side pins shorted together and detector side pins shorted together.

Individual Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
LED	Forward voltage	VF	I _F = ±100 mA	_	1.4	1.7	V
	Forward current	١ _F	V _F = ±0.7 V	_	2.5	20	μA
	Capacitance	CT	V = 0, f = 1 MHz	_	60	_	pF
Detector	Collector–emitter breakdown voltage	V _(BR) CEO	I _C = 0.5 mA	55		_	V
	Emitter-collector breakdown voltage	V _{(BR) ECO}	I _E = 0.1 mA	7	_	_	V
	Collector dark current	ICEO	V _{CE} = 24 V	-	10	100	nA
			V _{CE} = 24 V, Ta = 85°C	_	2	50	μA
	Capacitance collector to emitter	C _{CE}	V = 0, f = 1 MHz	_	10	—	pF

Coupled Electrical Characteristics (Ta = 25°C)

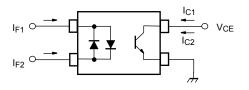
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
	I _C / I _F	I _F = ±20 mA, V _{CE} = 1 V	25	_	_	%
Current transfer ratio	I _C / I _F (high)	I _F = ±100 mA, V _{CE} = 1 V	20	_	80	
Collector-emitter		I _C = 2.4 mA, I _F = ±20 mA	_	_	0.4	V
saturation voltage	V _{CE (sat)}	I _C = 2.4 mA, I _F = ±100 mA	_	_	0.4	v
Off-state collector current	I _{C(off)}	V_{F} = ± 0.7V, V_{CE} = 24 V	_	1	10	μA
CTR symmetry (Note)	I _{C (ratio)}	$I_{C} (I_{F} = -20 \text{mA}) / I_{C} (I_{F} = +20 \text{mA})$ (Note)	0.5	1	2	_

Isolation Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Capacitance input to output	CS	V _S = 0, f = 1 MHz	—	0.8	_	pF
Isolation resistance	R _S	V _S = 500 V, R.H. ≤ 60%	5×10 ¹⁰	10 ¹⁴	_	Ω
		AC, 1 minute	5000	_	_	V
Isolation voltage	BVS	AC, 1 second, in oil	_	10000	_	V _{rms}
		DC, 1 minute, in oil	_	10000	_	V _{dc}

(Note)

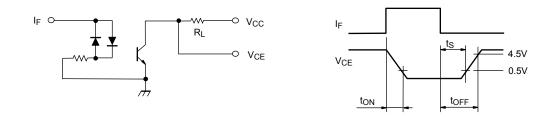
 $I_{C}(ratio) = \frac{I_{C2}(I_F = I_{F2}, V_{CE} = 1V)}{I_{C1}(I_F = I_{F1}, V_{CE} = 1V)}$



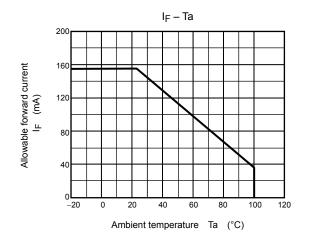
Switching Characteristics (Ta = 25°C)

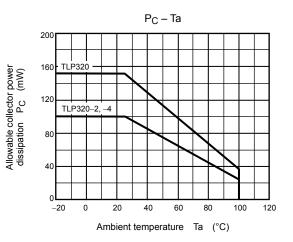
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Rise time	t _r		_	2	_	
Fall time	t _f	V _{CC} = 10 V, I _C = 2 mA	_	3	_	
Turn–on time	t _{on}	R _L = 100Ω	_	3	_	μs
Turn–off time	t _{off}		_	3	_	
Turn–on time	t _{ON}	$\mathbf{D}_{\mathbf{k}} = 1 0 \mathbf{k} 0 \qquad (Firs 1)$	_	2	_	
Storage time	ts	R_L = 1.9 kΩ (Fig.1) V _{CC} = 5 V, I _F = ±16 mA	_	15	_	μs
Turn-off time	tOFF	VCC - 5 V, IF - 10 IIIA	_	25	_	

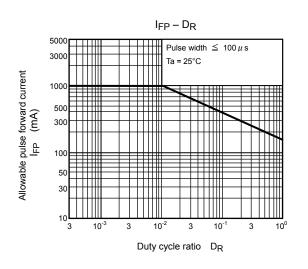
Fig. 1 Switching time test circuit

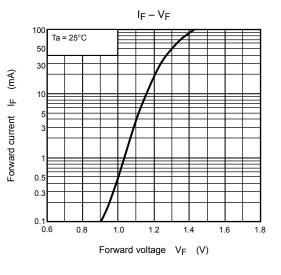


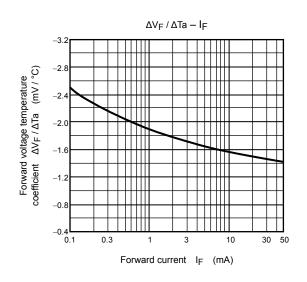
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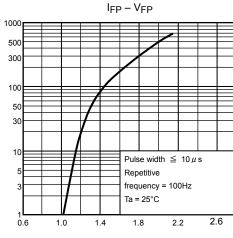












Pulse forward voltage V_{FP} (V)

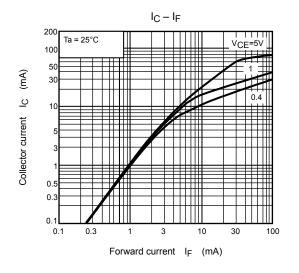
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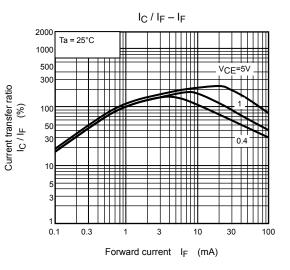
(mA)

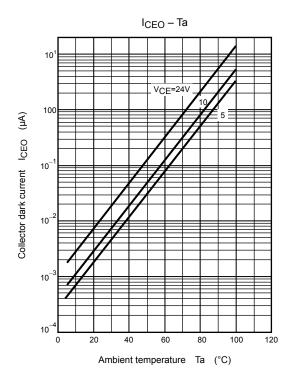
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Pulse forward current

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